Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:	
Plastic	
Overall Length:	
Between 0.120 inches and	d 0.240 inches
Terminal Length:	
0.500 inches	
Overall Width:	
0.222 inches	
Mounting Method:	
Terminal	
Semiconductor Material:	
Silicon	
Voltage Rating In Volts F	Per Characteristic:
50.0 on voltage, forward	voltage drop, dc
Current Rating Per Chara	acteristic:
20.00 milliamperes source	e cutoff current preset and 50.00 milliamperes forward current, average peak
Power Rating Per Charac	cteristic:
350.0 milliwatts small-sign	al input power, common-collector preset
Maximum Operating Ten	npurature Per Measurement Point:
125.0 degrees celsius amb	bient air
Test Data Document:	
89536-348482 drawing (th	nis is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.;
excludes any specification	n, standard or other document that may be referenced in a basic governing drawing)
Terminal Type And Quar	ntity:
2 uninsulated wire lead	
Shelf Life:	
N/a	
Unit Of Measure:	
Demilitarization:	
No	
Fiig:	
A110a0	